



PATENT APPLICATION

Atty. Docket No.:
Applicant:
Filing Date:

9898-217
Jae-Hyun Joo and Wan-Don Kim
January 22, 2002

Serial No. 10/055,270
Group: 2814

INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
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FOREIGN PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
<u>A.M</u>	_____	P2001-0026123	04/06/01	Korea	Jong Yong Yun
<u>A.M</u>	_____	P1999-0062504	07/26/99	Korea	Gabusikigaisha
<u>A.M</u>	_____	JP5102040	04/23/93	Japan	Toyko Electron Ltd.

OTHER DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
<u>A.M</u>	_____	English Abstract of P2001-0026123
<u>A.M</u>	_____	English Abstract of P1999-0062504
<u>A.M</u>	_____	English Abstract of JP5102040

Examiner: ANH D. MAH

Date Considered: 1/27/05.

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<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
<u>A.M</u>	_____	JP9102292	04/15/1997	Japan	Shin ETSU Chem. Co., Ltd.

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<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
<u>A.M</u>	_____	English Language Abstract of Japanese Patent No. JP9102292, filed 04/15/1997

Examiner: ANH D. MAIDate Considered: 1/27/05



PATENT APPLICATION
Docket No. 9898-217
Client No. SS-16232-US-RCE

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s): Jae-Hyun JOO and Wan-Don KIM Conf. No. 6757
Serial No.: 10/055,270 Examiner: Mai, Anh, D.
Filing Date: January 22, 2002 Group Art Unit: 2814
Title: METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE HAVING A
METAL-INSULATOR CAPACITOR

INFORMATION DISCLOSURE CITATION
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FOREIGN PATENT DOCUMENTS

Exam Init	Ref	Document Number	Publication Date	Country	Name
<u>A.M.</u>	<u> </u>	JP5102040	4/23/1993	Japan	Horiike
		JP11087629	3/30/1999	Japan	Kijiro

OTHER DOCUMENTS

Exam Init	Ref	Author, Title, Date, Pertinent Pages, Etc.)
<u>A.M.</u>	<u> </u>	English Language Abstract of Japanese Patent No. JP5102040.
		English Language Abstract of Japanese Patent No. JP11087629.

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